

AlGaAs/GaAs Red Chip ---TK0110DRN

1. Scope

- The specification applies to AlGaAs LED chips.
- Type : TK0110DRN.

2. Structure

- AlGaAs/GaAs red LED chip.
- N/P mesa type.
- Electrode N (cathode) side : Aluminum or Gold.
- Electrode P (anode) side : Gold alloy.

3. Size

- Chip size : $250\mu\text{m} \times 250\mu\text{m}$
- Chip height : $280\mu\text{m} \pm 30\mu\text{m}$
- Pattern drawing : per fig. 1

4. Electro-Optical Characteristics

($T_a = +25^\circ\text{C}$)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Forward Voltage	V_F	$I_F = 20\text{mA}$		1.82	2.00	V
Reverse Voltage	V_R	$I_R = 10\mu\text{A}$	5			V
Luminous Intensity	I_V	$I_F = 20\text{mA}$	10.0	※		mcd
Wavelength	λ_p / λ_d	$I_F = 20\text{mA}$		655/640		nm
Spectrum Width of Half Value	$\Delta \lambda$	$I_F = 20\text{mA}$		20		nm

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- Rank D : $20.0 \leq \text{avg.} < 25.0$ mcd
 - Rank E : $25.0 \leq \text{avg.} < 30.0$ mcd
 - Rank F : $30.0 \leq \text{avg.} < 35.0$ mcd
 - Rank G : $\text{avg.} \geq 35.0$ mcd

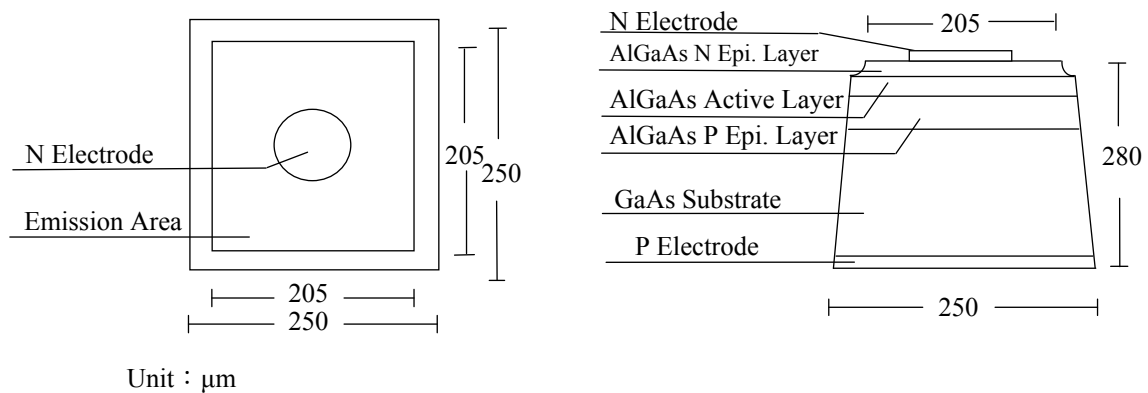


fig. 1

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☐ TYNTEK Head Office
☐ TYNTEK Chunan Branch
[http : //www.tyntek.com.tw](http://www.tyntek.com.tw)

Tel : 886-3-5781616
Tel : 886-37-582997

Fax : 886-3-5780545
Fax : 886-37-582908

E-mail : service@serv.tyntek.com.tw

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Electro-Optical Characteristics Curve

